

SEMICONDUCTOR

TN6707A

NPN General Purpose Amplifier

- These devices is designed for general purpose medium power amplifiers and switches requiring collector currents to 1.0A
- Sourced from process 39.



Absolute Maximum Ratings* T_A=25°C unless otherwise noted

Symbol	Parameter	FPN660	Units
V _{CEO}	Collector-Emitter Voltage	80	V
V _{CBO}	Collector-Base Voltage	100	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	1.2	A
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150°C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

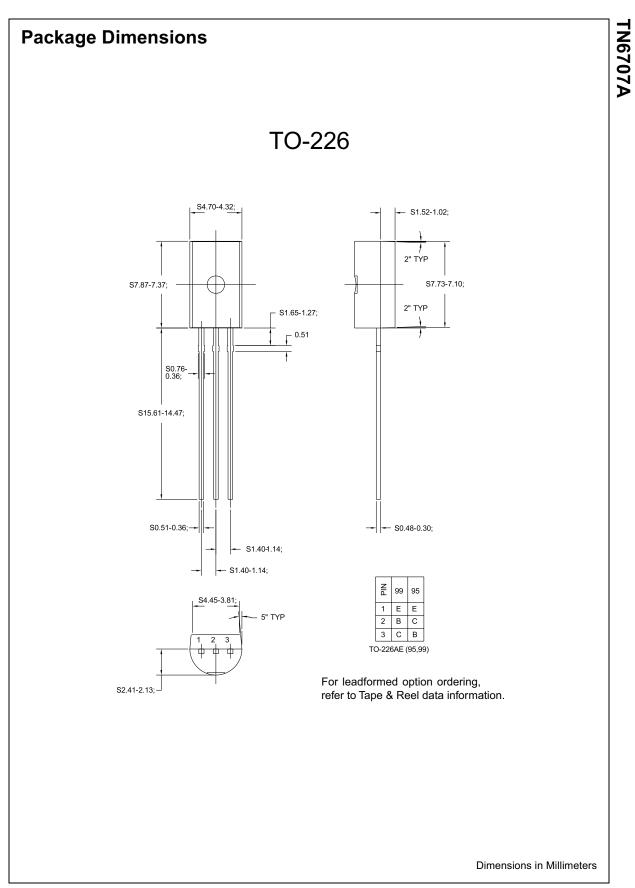
Electrical Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Max.	Units	
Off Charac	cteristics	•		•		
V _{(BR)CEO} Collector-Emitter Breakdown Voltage *		I _C = 10mA, I _B = 0	80		V	
V _{(BR)CBO} Collector-Base Breakdown Voltage		$I_{\rm E} = 100\mu A, I_{\rm E} = 0$			V	
V _{(BR)EBO} Emitter-Base Breakdown Voltage		I _E = 1.0mA, I _C = 0	5.0		V	
I _{CBO} Collector-Base Cutoff Current		V _{CB} = 80V, I _E = 0		0.1	μA	
I _{EBO}	Emitter-Base Cutoff Current	V _{EB} = 5.0V, I _C = 0		0.1	μA	
On Characteristics *						
h _{FE}	DC Current Gain	V _{CE} = 2.0V, I _C = 50mA	40			
		V _{CE} = 2.0V, I _C = 250mA	40	250		
		V _{CE} = 2.0V, I _C = 500mA	25			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 500mA, I _B = 50mA		0.5	V	
		I _C = 1.0A, I _B = 100mA		1.0	V	
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} = 2.0V, I _C = 1.0A		1.5	V	
Small Sigr	nal Characteristics	·				
h _{fe} Output Capacitance		V _{CE} = 5.0V, I _C = 200mA, f = 20MHz	2.5	20	MHz	
f _T	Current Gain Bandwidth Product	V _{CE} = 5.0V, I _C = 50mA, f = 20MHz	50		MHz	

Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2.0%

Thermal Characteristics $T_A=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max.	Units
P _D Total Device Dissipation		1.0	W
	Derate above 25°C	8.0	mW/°C
R _{0JC} Thermal Resistance, Junction to Case		50	°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	125	°C/W



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